## NSN 5961-01-257-4057

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-257-4057 **Inclosure Material:** Ceramic **Overall Length:** 0.786 inches **Terminal Length:** 0.125 inches **Overall Height:** 0.200 inches **Overall Width:** 0.310 inches **Response Time:** 1.0 microseconds all transistor **Component Name And Quantity:** 7 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 50.0 collector to emitter voltage, dc all transistor and 6.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 25.00 milliamperes source cutoff current all transistor and 500.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 1.5 watts small-signal input power, common-collector absolute all transistor **Capacitance Rating In Picofarads:** 25.0 all transistor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 16 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

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